

STTH112

High voltage ultrafast rectifier

Features

- Low forwarded voltage drop
- High reliability
- High surge current capability
- Soft switching for reduced EMI disturbances
- Planar technology

Description

The STTH112, which is using ST ultrafast high voltage planar technology, is specially suited for free-wheeling, clamping, snubbering, demagnetization in power supplies and other power switching applications

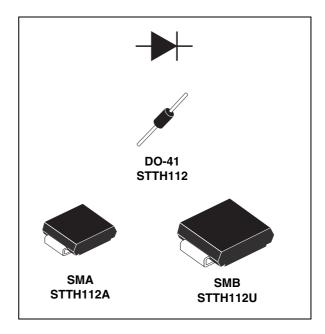


Table 1. Device summary

Symbol	Value
I _{F(AV)}	1 A
V_{RRM}	1200 V
T _{j (max)}	175 °C
V _{F (max)}	1.65 V

Electrical characteristics STTH112

1 Electrical characteristics

Absolute ratings (limiting values)

Symbol	Parameter		Value	Unit		
V_{RRM}	Repetitive peak reverse voltage		1200	V		
V _(RMS)	Voltage rms				850	V
		TI = 85°C	δ =0.5	DO-41		
I _{F(AV)}	I _{F(AV)} Average forward current		δ =0.5	SMA	1	Α
		TI = 125°C	δ =0.5	SMB		
				DO-41	20	
I _{FSM}	Forward surge current t = 8.3 ms			SMA	10	Α
				SMB	18	
T _{stg}	Storage temperature range				- 50 + 175	°C
T _j	Maximum operating junction temperature				+ 175	°C

Table 2. Thermal parameters

Symbol	Parameter			Value	Unit
		L = 10 mm	DO-41	45	
R _{th (j-l)}	Junction to lead		SMA	30	°C/W
			SMB	25	C/VV
R _{th (j-a)}	Junction to ambient	L = 10 mm	DO-41	110	

Table 3. Static electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I_	Reverse leakage current	V _R = 1200 V	T _j = 25 °C			5	μA
I _R	neverse leakage current	v _R = 1200 v				50	μΑ
			T _j = 25 °C			1.9	
V_{F}	Forward voltage drop	I _F = 1 A	T _j = 125 °C		1.17	1.65	V
			T _j = 150 °C		1.10	1.55	

Table 4. Dynamic electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
t _{rr}	Reverse recovery time	$I_F = 0.5 A$ $I_{rr} = 0.25 A I_R = 1A$	T _j = 25 °C			75	ns
t _{fr}	Forward recovery time	I _F = 1 A	T 05.00			500	ns
V _{FP}	Forward recovery voltage	dl _F /dt = 50 A/μs V _{FR} = 1.1 x V _{Fmax}	T _j = 25 °C			30	V

Figure 1. Conduction losses versus average Figure 2. Forward voltage drop versus current forward current

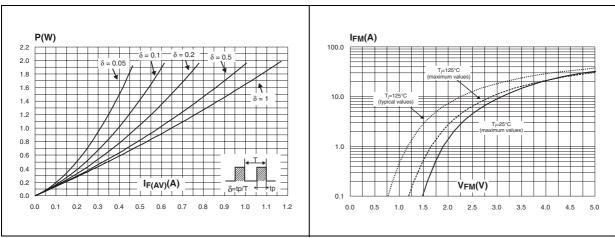


Figure 3. Relative variation of thermal impedance junction ambient versus pulse duration (DO-41)

Figure 4. Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4) (SMA)

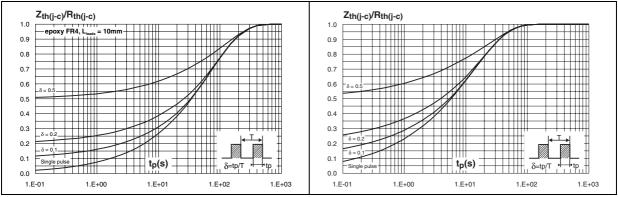
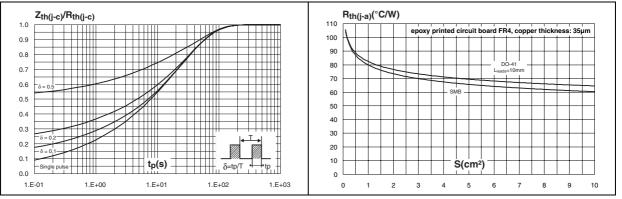


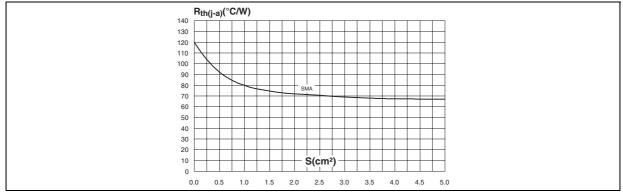
Figure 5. Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4)(SMB)

Figure 6. Thermal resistance junction to ambient versus copper surface under each lead (DO-41, SMB)



Electrical characteristics STTH112

Figure 7. Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed circuit board FR4, copper thickness: 35µm) (SMA)



4/8

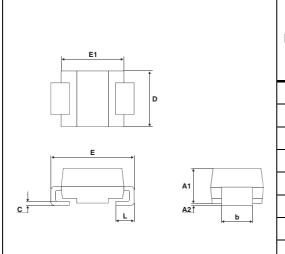
STTH112 Package information

2 Package information

- Epoxy meets UL 94, V0
- Band indicates cathode
- Bending method (DO-41): see Application note AN1471

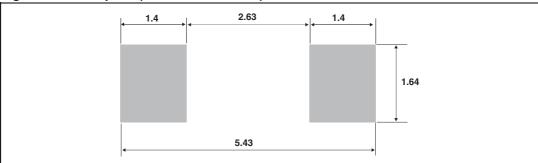
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 5. SMA dimensions



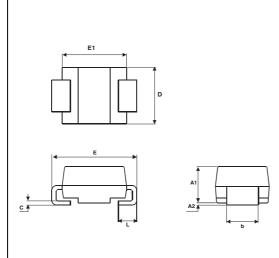
	Dimensions				
Ref.	Millim	Millimeters In		hes	
	Min.	Max.	Min.	Max.	
A1	1.90	2.45	0.075	0.094	
A2	0.05	0.20	0.002	0.008	
b	1.25	1.65	0.049	0.065	
С	0.15	0.40	0.006	0.016	
D	2.25	2.90	0.089	0.114	
Е	4.80	5.35	0.189	0.211	
E1	3.95	4.60	0.156	0.181	
L	0.75	1.50	0.030	0.059	

Figure 8. Footprint (dimensions in mm)



Package information STTH112

Table 6. SMB dimensions



	Dimensions					
Ref.	Millimeters		Inc	hes		
	Min.	Max.	Min.	Max.		
A1	1.90	2.45	0.075	0.096		
A2	0.05	0.20	0.002	0.008		
b	1.95	2.20	0.077	0.087		
С	0.15	0.40	0.006	0.016		
D	3.30	3.95	0.130	0.156		
Е	5.10	5.60	0.201	0.220		
E1	4.05	4.60	0.159	0.181		
L	0.75	1.50	0.030	0.059		

Figure 9. Footprint (dimensions in mm)

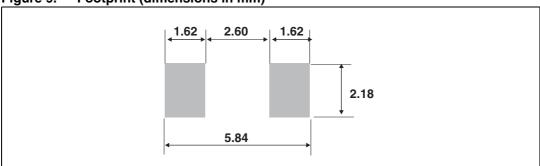
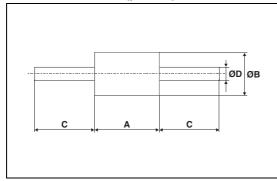


Table 7. DO-41 (plastic) dimensions



	Dimensions					
Ref.	Millim	neters	Inc	hes		
	Min.	Max.	Min.	Max.		
Α	4.07	5.20	0.160	0.205		
В	2.04	2.71	0.080	0.107		
С	25.4		1			
D	0.71	0.86	0.028	0.034		

3 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery Mode
STTH112	STTH112	DO-41	0.34 g	2000	Ammopack
STTH112A	H12	SMA	0.068 g	5000	Tape and reel
STTH112U	U12	SMB	0.11 g	2500	Tape and reel
STTH112RL	STTH112	DO-41	0.34 g	5000	Tape and reel

4 Revision history

Table 9. Document revision history

Date	Revision	Changes
Jan-2003	2	Initial release.
22-Jun-2005	3	New value of T_j = 150 °C added to table 2. Dimensions A1 E and D updated in Table 4. Data sheet reformatted. No other technical changes.
20-Mar-2007	4	Reformatted to current standards. Updated dimensions and footprints for SMA and SMB packages.
30-Sep-2009	5	Updated table 7 package dimensions.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2009 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

STMicroelectronics:

STTH112RL STTH112U STTH112A